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	SEMI CONDUCTOR

#### **PJX8802** 20V N-Channel Enhancement Mode MOSFET – ESD Protected SOT-563 Unit : inch(mm) Voltage 20 V Current 0.7A 0.011(0.27) 0.006(0.17) 0.067(1.70) 0.059(1.50) Features 0.035(0.90) RDS(ON), VGS@4,5V, ID@0.7A<150mΩ</li> RDS(ON), VGS@2.5V, ID@0.5A<220mΩ 0.052(1.30) 0.024(0.60) 0.043(1.10) 0.067(1.70) RDS(ON), VGS@1.8V, ID@0.2A<400mΩ . 0.059(1.50) Advanced Trench Process Technology 0.007(0.17) Specially Designed for Load Switch or PWM application. ESD Protected 2KV HBM • Lead free in compliance with EU RoHS 2011/65/EU directive Green molding compound as per IEC61249 Std. 0.012(0.30) (Halogen Free) D1 G2 **Mechanical Data** 6 5 • Case: SOT-563 Package Terminals: Solderable per MIL-STD-750, Method 2026 • Approx. Weight: 0.00009 ounces, 0.0026 grams Marking: X02 3 2 D2G

### **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>GS</sub>	<u>+</u> 8	V	
Continuous Drain Current	I <sub>D</sub>	0.7	А	
Pulsed Drain Current		I <sub>DM</sub>	2.8	А
Power Dissipation	T <sub>a</sub> =25°C	PD	300	mW
	Derate above 25°C		2.4	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance - Junction to Ambient <sup>(Note 3)</sup>		R <sub>eja</sub>	417	°C/W



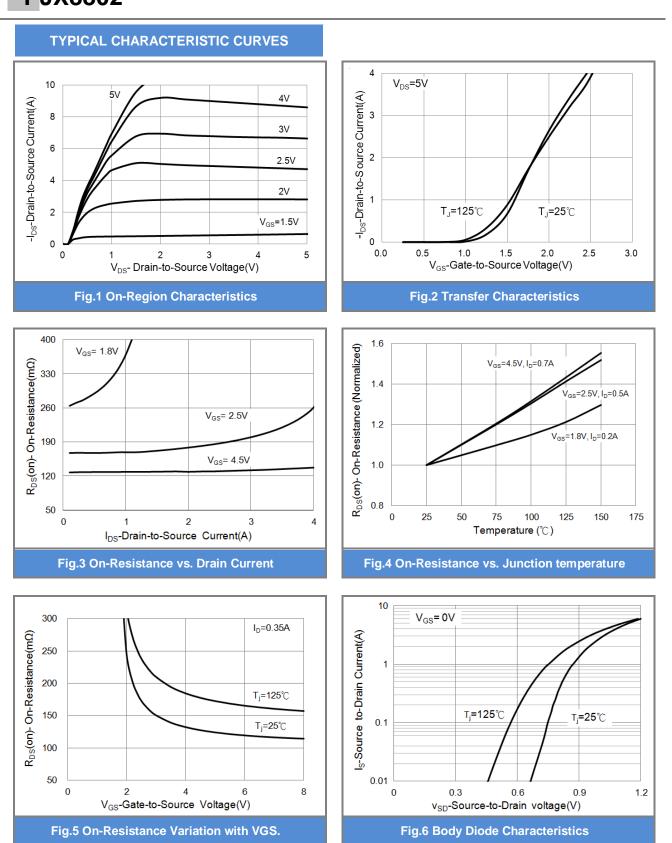
### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

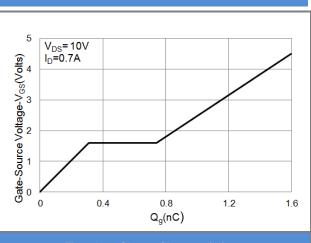
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}$ =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	0.5	0.78	1.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =0.7A	-	129	150	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =0.5A	-	167	220	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =0.2A	-	260	400	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =20V, $V_{GS}$ =0V	-	0.01	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 8V, V <sub>DS</sub> =0V	-	<u>+</u> 2	<u>+</u> 10	uA
Dynamic						
Total Gate Charge	$Q_{g}$	V <sub>DS</sub> =10V, I <sub>D</sub> =0.7A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	1.6	-	nC
Gate-Source Charge	$Q_gs$		-	0.3	-	
Gate-Drain Charge	$Q_gd$		-	0.4	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	92	-	pF
Output Capacitance	Coss		-	25	-	
Reverse Transfer Capacitance	Crss		-	9	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>		-	6	-	
Turn-On Rise Time	tr	$V_{DD}=10V, I_{D}=0.7A,$	-	26	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=4.5V,$ R <sub>G</sub> =6 $\Omega^{(Note 1,2)}$	-	41	-	
Turn-Off Fall Time	tf	$R_{G}=6\Omega$	-	31	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	1-		_	_	0.4	Α
Diode Forward Current	l <sub>s</sub>		-	-	0.4	~
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.89	1.2	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>®JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited







**TYPICAL CHARACTERISTIC CURVES** 

Fig.7 Gate-Charge Characteristics

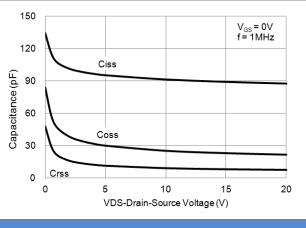
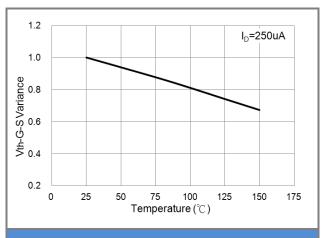


Fig.9 Capacitance vs. Drain-Source Voltage





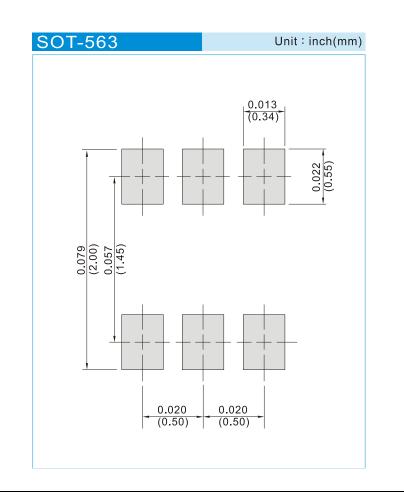




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJX8802_R1_00002	SOT-563	4K pcs / 7" reel	X02	Halogen free
PJX8802_R2_00002	SOT-563	10K pcs / 13" reel	X02	Halogen free

#### MOUNTING PAD LAYOUT







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